

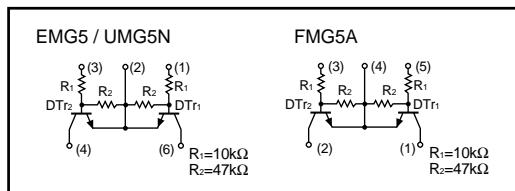
Emitter common (dual digital transistors)

EMG5 / UMG5N / FMG5A

●Features

- Two DTC114Y chips in a EMT or UMT or SMT package.

●Equivalent circuit



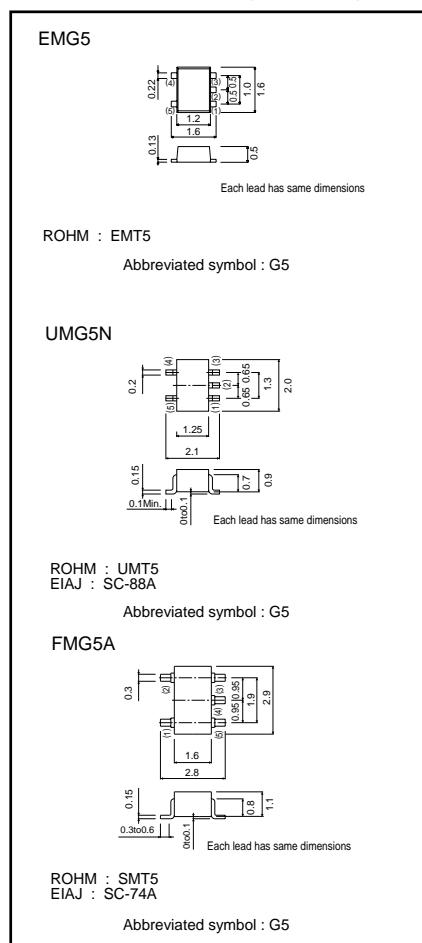
●Absolute maximum ratings ($T_a = 25^\circ\text{C}$)

Parameter	Symbol	Limits	Unit
Supply voltage	V _{CC}	50	V
Input voltage	V _{IN}	40 -6	V
Output current	I _O	100	mA
	I _C (Max.)	100	
Power dissipation	P _D	150 (TOTAL) 300 (TOTAL)	mW *1 *2
Junction temperature	T _J	150	°C
Storage temperature	T _{STG}	-55~+150	°C

*1 120mW per element must not be exceeded.

*2 200mW per element must not be exceeded.

●External dimensions (Units : mm)



EMG5 / UMG5N / FMG5A

Transistors

● Electrical characteristics ($T_a = 25^\circ C$)

Parameter	Symbol	Min.	Typ.	Max.	Unit	Conditions
Input voltage	V_I (off)	—	—	0.3	V	$V_{CC}=5V$, $I_o=100\mu A$
	V_I (on)	1.4	—	—		$V_o=0.3V$, $I_o=1mA$
Output voltage	V_o (on)	—	0.1	0.3	V	$I_o=5mA$, $I_l=0.25mA$
Input current	I_l	—	—	0.88	mA	$V_l=5V$
Output current	I_o (off)	—	—	0.5	μA	$V_{CC}=50V$, $V_l=0V$
DC current gain	G_i	68	—	—	—	$V_o=5V$, $I_o=5mA$
Transition frequency	f_T	—	250	—	MHz	$V_{CE}=-10V$, $I_e=5mA$, $f=100MHz$ *
Input resistance	R_i	7	10	13	k Ω	—
Resistance ratio	R_2/R_1	3.7	4.7	5.7	—	—

* Transition frequency of the device

● Packaging specifications

Type	Package	Taping		
		Code	T2R	TR
Type	Basic ordering unit (pieces)	8000	3000	3000
EMG5		○	—	—
UMG5N		—	○	—
FMG5A		—	—	○